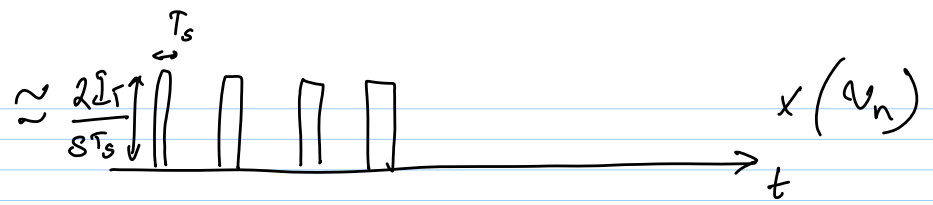
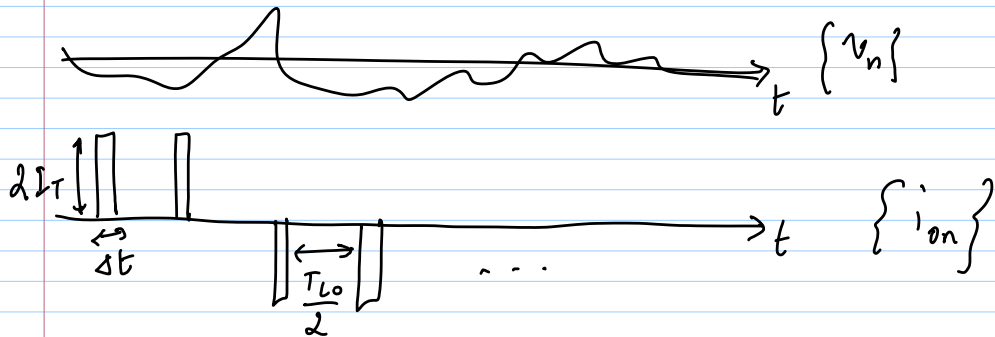


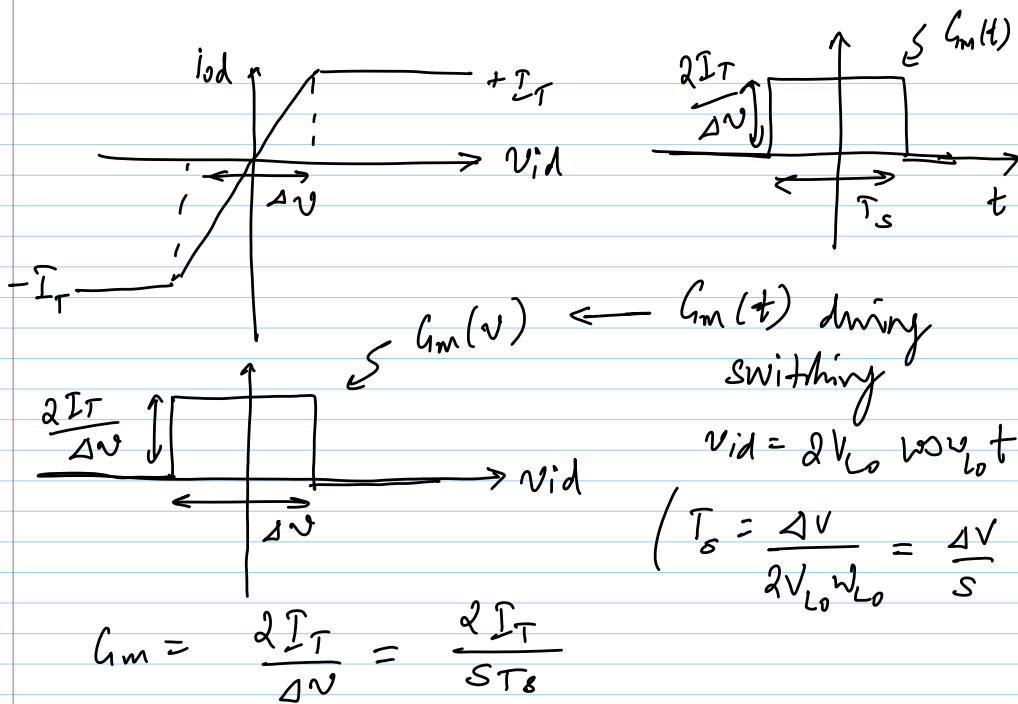
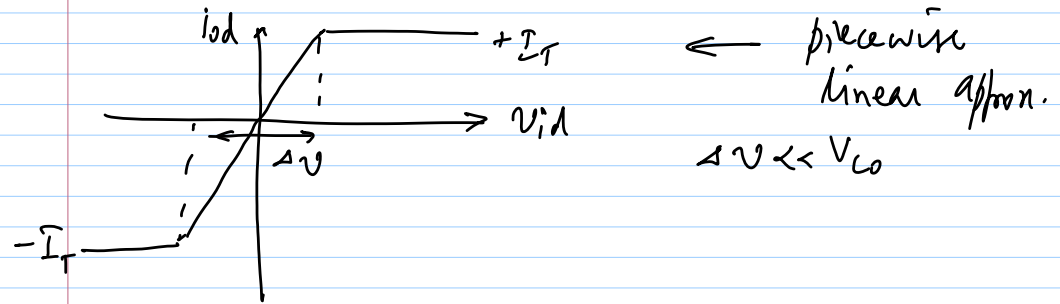
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Ref: "Noise in RF CMOS Mixers: A Simple Physical Model", IEEE JSSC, pp 15-25, Jan 2000



T_s = time during switching when both devices are turned on.
 - calculated from I-V char.



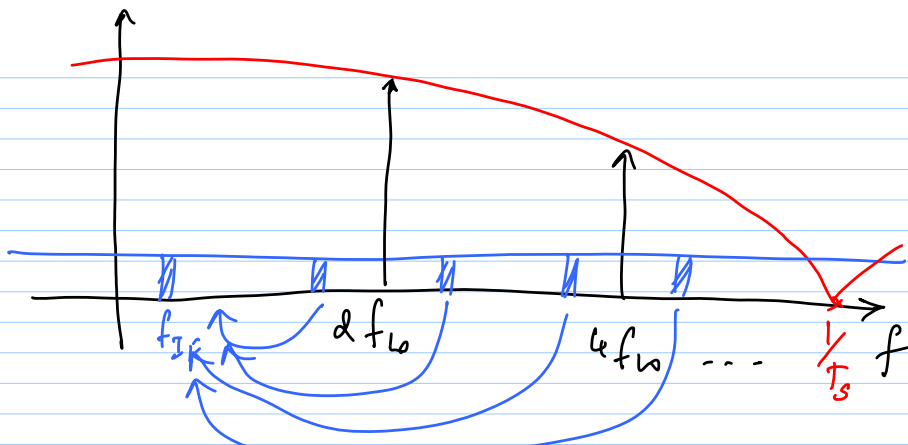
$$\frac{\overline{V_n^2}}{\Delta f} = \frac{4kT\gamma}{G_m}$$

It can be shown that:

$$\overline{i_{on,sw}^2} = \frac{2}{T_{Lo}} \cdot \left(\frac{2I_T}{S}\right)^2 \cdot \frac{1}{T_s} \cdot \overline{V_n^2}$$

$$\overline{i_{on,sw}^2} = 4kT\gamma \cdot \frac{I_T}{T_{Lo} V_{Lo}} \left\{ \begin{array}{l} \text{for sine} \\ \text{LO signal} \end{array} \right\}$$

* independent of L_o size



Total Output Noise

$$\overline{v_{on}^2} = \overline{v_{on,R_L}^2} + \overline{v_{on,g_m}^2} + \overline{v_{on,sw}^2}$$

$$= 8kTR_L + 4kT\gamma g_m R_L^2 + 8kT\gamma R_L^2 \cdot \frac{I_T}{\pi V_{L0}}$$

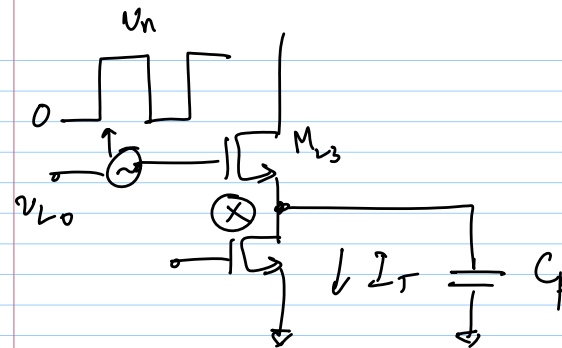
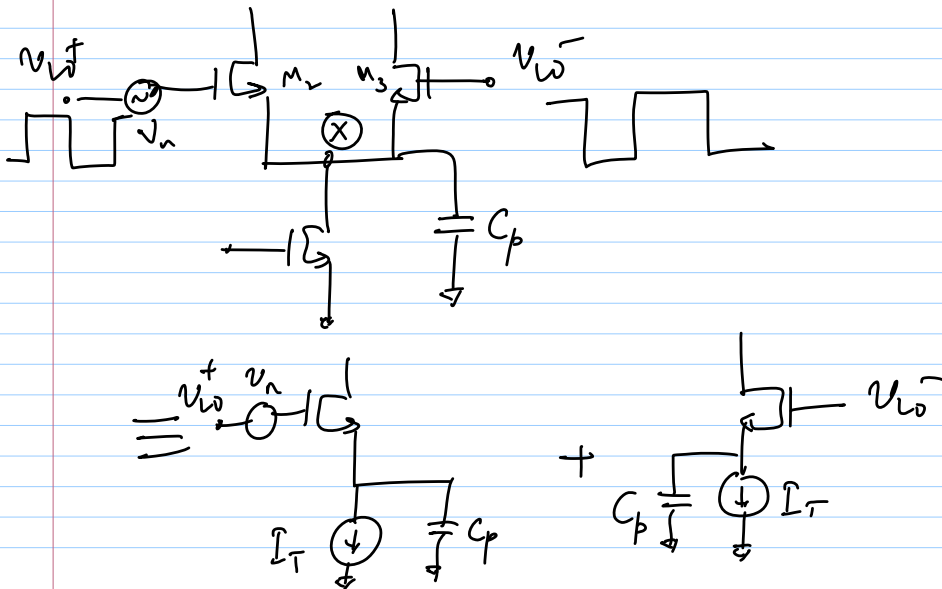
$$= 8kTR_L \left\{ 1 + \frac{\gamma g_m R_L}{2} + \frac{\gamma R_L I_T}{\pi V_{L0}} \right\}$$

Optimisation

$$\overline{v_{on}^2} = 8kTR_L \left\{ 1 + \frac{\gamma R_L \cdot I_T}{2(V_{as} - V_T)} + \frac{\gamma R_L I_T}{\pi V_{L0}} \right\}$$

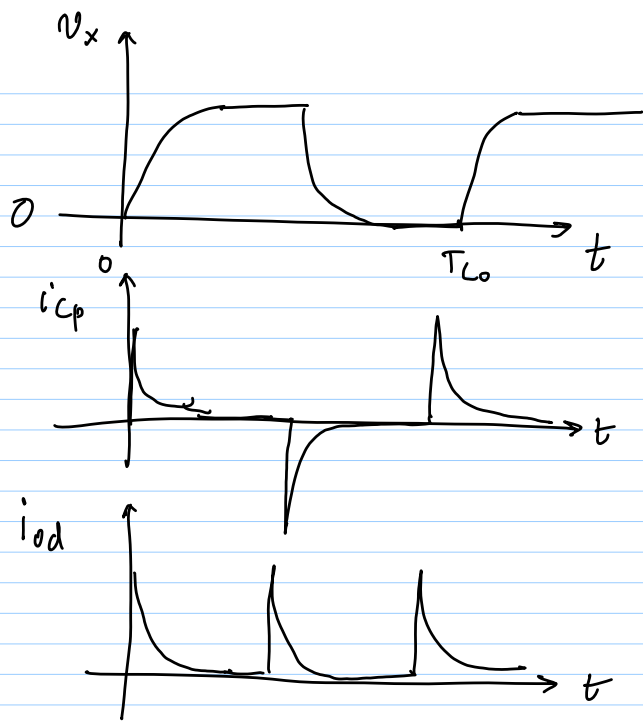
* SW & g_m relative contributions:
 $\frac{2(V_{as} - V_T)}{\pi V_{L0}} \sim 1$ optimum while keeping good linearity

b) indirect switch noise



$v_n \ll V_{L0} \rightarrow$ linear

$$\tau_x \sim \frac{C_p}{g_{m_{2,3}}} \ll \tau_{L0}$$



$f_{\text{rev}} = f_{L0}$
 $i_{cp}(DC) = 0$

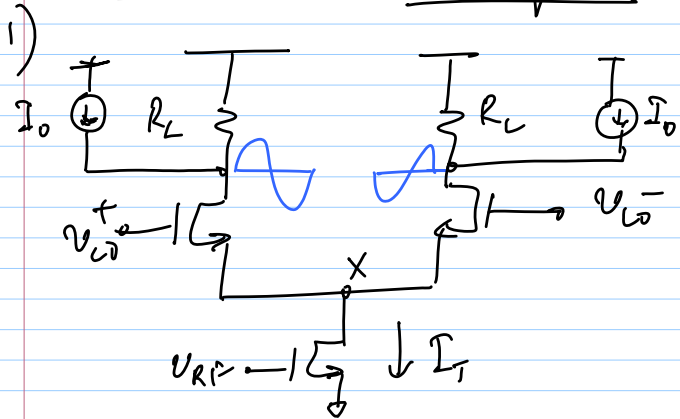
$f_{\text{rev}} = 2f_{L0}$,
 finite DC

$$\begin{aligned}
 \overline{i_{on}} &= \frac{2}{T_{L0}} \int_0^{T_{L0}/2} i_{cp}(t) dt \\
 &= \frac{2}{T_{L0}} \int_0^{T_{L0}/2} C_p \left[\frac{dV_x(t)}{dt} \right] dt \\
 &= \frac{2}{T_{L0}} C_p [V_x(T_{L0}/2) - V_x(0)] \\
 &= \frac{2C_p}{T_{L0}} \overline{V_n}
 \end{aligned}$$

$$G_c = \frac{2C_p}{T_{L0}} = 2f_{L0} C_p$$

→ ↑ with f_{L0}

Additional techniques



$V_{R_L} = I_T R_L / 2$
 * Linearity depends on $(V_{as} - V_T) I_0$ dev.

2)

